NSN 5961-00-809-1871



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-809-1871 **Inclosure Material:** Metal **Overall Length:** 0.443 inches **Overall Diameter:** 0.375 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 6.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud **Specification Data:** 80131-release3376 professional/industrial association specification Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

NSN 5961-00-809-1871 Transistor - Page 2 of 2



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